

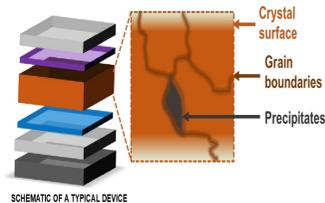
Dr. Juan-Pablo Correa-Baena



- Juan-Pablo Correa-Baena joined Georgia Tech in the Spring of 2019. His group focuses on the understanding and control of electronic dynamics at the nanoscale for low-cost semiconductors, such as halide perovskites and other materials.
- Juan-Pablo received his PhD from the University of Connecticut, where he studied metal oxide aerogels as porous conductive electrodes for dye-sensitized solar cells, funded by two National Science Foundation fellowships.
- His work as a postdoctoral fellow at the Ecole Polytechnique Fédérale de Lausanne focused on understanding of fundamental questions regarding band alignment at interfaces and their influence on performance in perovskite solar cells.
- His work at MIT shed light onto minority phase formation and elemental distribution in complex, multi-element halide perovskites, which determine the efficiency of the solar cells. His contributions have ultimately helped boost the efficiencies of perovskite solar cells above 25%.

Research Focus

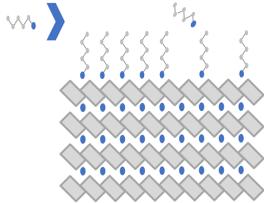
Understand



The role of interfaces and of 2D and 3D defects in low-cost semiconductors

- Advanced X-ray and neutron characterization

Design



Device fabrication with monolayer control and large area uniformity

- Vapor deposition of perovskites and charge extraction layers

Evaporation

- Scalability remains an obstacle towards commercialization of perovskite solar cells (PSCs)
 - PSCs are composed of many layers traditionally deposited via spin-coating
 - Use of solvents remains an issue due to concerns over toxicity, low solubility of precursors, and potential dissolving of underneath layers
 - Our research is focused on fabrication of PSCs by physical vapor deposition (thermal evaporation techniques)
 - Benefits of thermal evaporation include high purity films, large area compatibility, and better thickness control
- Coevaporation of perovskite precursors allows for control over the resulting stoichiometry

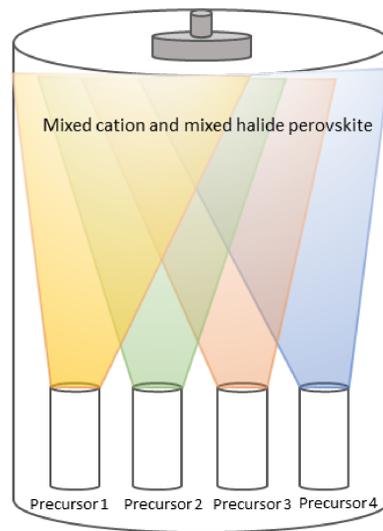


Figure 1. Coevaporation of mixed cation and mixed halide perovskites

Andres Felipe Castro Mendez Carlo Perini



Atomic Layer Deposition

- Atomic layer deposition (ALD) allows for uniform deposition of very thin films with angstrom-level thickness control
- Sequential, self-limiting process (see Fig. 2)
- Allows for deposition of thin passivation layers
- Our research focuses on the design of an ALD process for the deposition of lead iodide and perovskite
- Another aim is the optimization of charge transport layers

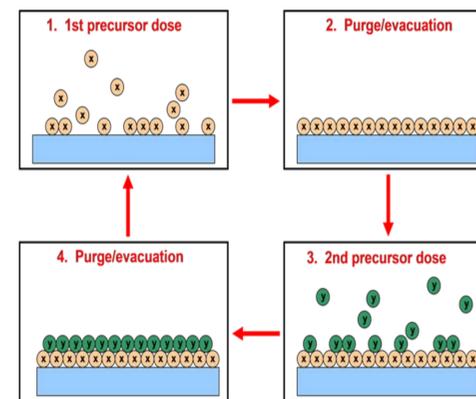


Figure 2. A typical ALD process (Kurt J Lesker Company)

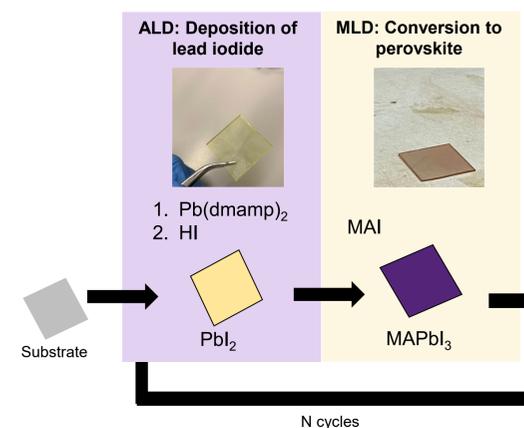


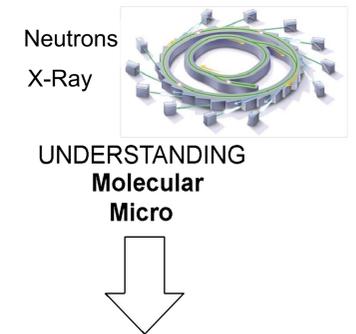
Figure 3. ALD/MLD of perovskite

Jake Vagott



Synchrotron

Advanced characterization techniques



Macro: PEROVSKITE SOLAR CELL

- GIWAXS/GISAXS
- Hybrid organic-inorganic perovskites are promising for solar cell applications due to their high conversion efficiency
- Using neutron and synchrotron advanced characterization techniques, a deep analysis of the material can be realized including the following information:
 - Material structure
 - Chemical state/bonding
 - Elemental distribution
 - In-situ* changes due to environmental conditions

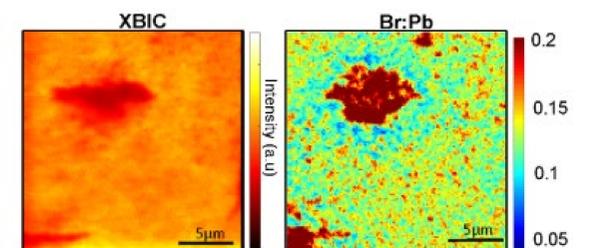


Figure 4. XBI and XRF ratio of Br:Pb in a triple cation CsMAFA perovskite (Experiment done at beamline 2ID-D at the APS at Argonne National Laboratory)

Juanita Hidalgo



Carlo Perini

